

Received: 28 December 2016 Accepted: 16 May 2017 Published online: 23 June 2017

# **OPEN** Effect of H<sub>2</sub>O Adsorption on **Negative Differential Conductance Behavior of Single Molecular Junction**

Zong-Liang Li, Xiao-Hua Yi, Ran Liu, Jun-Jie Bi, Huan-Yan Fu, Guang-Ping Zhang , Yu-Zhi Song & Chuan-Kui Wang

Large negative differential conductance (NDC) at lower bias regime is a very desirable functional property for single molecular device. Due to the non-conjugated segment separating two conjugated branches, the single thiolated arylethynylene molecule with 9,10-dihydroanthracene core (denoted as TADHA) presents excellent NDC behavior in lower bias regime. Based on the  $\alpha b$  initio calculation and non-equilibrium Green's function formalism, the NDC behavior of TADHA molecular device and the H<sub>2</sub>O-molecule-adsorption effects are studied systematically. The numerical results show that the NDC behavior of TADHA molecular junction originates from the Stark effect of the applied bias which splits the degeneration of the highest occupied molecular orbital (HOMO) and HOMO-1. The H<sub>2</sub>O molecule adsorbed on the terminal sulphur atom strongly suppresses the conductance of TADHA molecular device and destroys the NDC behavior in the lower bias regime. Single or separated H<sub>2</sub>O molecules adsorbed on the backbone of TADHA molecule can depress the energy levels of molecular orbitals, but have little effects on the NDC behavior of the TADHA molecular junction. Aggregate of several H<sub>2</sub>O molecules adsorbed on one branch of TADHA molecule can dramatically enhance the conductance and NDC behavior of the molecular junction, and result in rectifier behavior.

Utilizing single molecule as functional device in electronic circuit is an ultimate goal of molecular electronics, which has motivated scientists to devote themselves to the investigations of molecular devices for tens of years<sup>1-10</sup>. Due to the rapid development of single molecular technologies<sup>11-14</sup>, great progresses have been achieved for single-molecule-device fabrications in recent years 15-18. At the meantime, different strategies are designed to control and improve the functional properties of single molecular device<sup>19–22</sup>. In order to gain insights into the controlling mechanism of single molecular functional characteristics<sup>23–25</sup>, the effects of external ambient<sup>26–28</sup>, electrode distance<sup>29, 30</sup>, molecule-electrode interface<sup>31–35</sup>, molecular anchor<sup>36–43</sup>, side group<sup>44–47</sup>, doping<sup>48, 49</sup> and  $external\ field^{50-55}\ have\ been\ studied\ intensively.\ In\ experimental\ studies,\ molecular\ devices\ are\ often\ fabricated$ in solution and measured in vacuum or in gas circumstance, thus the effect of the surrounding molecule on the functional properties of molecular device should also be discussed 56-59. Generally, the surrounding molecules play negative effects on the molecular junction, for example, aqueous solution or the water vapor can suppress the electronic transport of molecular junction dramatically 28, 56-58. However, sometimes the surrounding molecules can also have positive effects, our recent research reveals that the small ambient molecules can make molecular junction more stable due to their suppressing the thermal vibrations of the molecular junction <sup>14</sup>. Therefore, studying the influence of surrounding molecules on molecular device is very helpful to improve the functional characteristics of the molecular device by properly applying surrounding molecules.

Due to the non-conjugated segment separating two conjugated arms, the single thiolated arylethynylene molecule with 9,10-dihydroanthracene core (denoted as TADHA) shows pronounced negative differential conductance (NDC) behavior, which has recent been detected by Perrin et al. 60. Although the NDC behavior of single molecular device is often presented in theoretical studies, it is very scarce in experimental findings, and the NDC often shows very small for most cases. Thus, it is significant that Perrin et al. fabricated single TADHA molecular junction with large NDC behavior, especially the NDC behavior was occurred at lower bias regime

School of Physics and Electronics, Shandong Normal University, Jinan, 250014, China. Correspondence and requests for materials should be addressed to Z.-L.L. (email: lizongliang@sdnu.edu.cn)

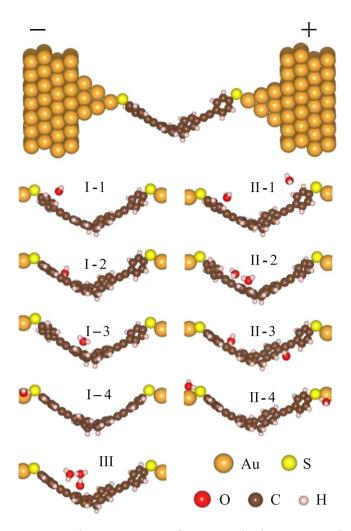
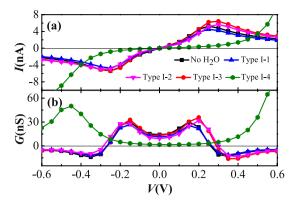


Figure 1. Schematic structures of TADHA molecular junctions with  $\rm H_2O$  molecule being adsorbed on different sites.

because high bias voltage may deform the configuration of molecular junction <sup>14</sup>. Considering that the molecular junction was fabricated in solution, we are very interested in that if the junction is not absolutely dried, *i.e.*, if one or several H<sub>2</sub>O molecules are left and adsorbed on the functional molecule, whether the NDC behavior can be destroyed or be enhanced? In order to answer this question, according to the density functional theory (DFT), we simulated the adsorptions of H<sub>2</sub>O molecules on different positions of the TADHA molecule. Then by applying non-equilibrium Green's function (NEGF) formalism, the electronic transport properties of TADHA molecular junction were studied with the influences of H<sub>2</sub>O adsorbates. Our study shows that, the H<sub>2</sub>O molecules adsorbed on the terminal sulphur atoms not only destroy the NDC behavior of TADHA molecular device, but also depress the current of the molecular junction distinctly at lower bias regime. The NDC behavior of TADHA molecular device seems to show some water-immunity character for single or separated H<sub>2</sub>O molecules adsorbed on the backbone of TADHA molecule, but it is very sensitive to the aggregate of several H<sub>2</sub>O molecules. Our findings are valuable to the fabrication of TADHA molecular junction in solvent, *i.e.*, one can determine whether there are H<sub>2</sub>O molecules adsorbed on the terminal S atoms or aggregate of H<sub>2</sub>O molecules adsorbed on the backbone of functional molecule by the electronic transport properties of molecular junction in experiment.

#### Results

One  $H_2O$  molecule adsorption. In order to simulate the TADHA molecular junction and study the  $H_2O$  effect, we constructed Au-Molecule-Au systems by sandwiching TADHA molecule between two gold electrodes with one or several  $H_2O$  molecules adsorbed on different sites of TADHA molecule as shown in Fig. 1. As for one- $H_2O$ -adsorption samples, based on the geometric optimizations, we found that there are four typical sites for  $H_2O$  molecule to be adsorbed on, *i.e.*, (1) the aryl ring site on one arm of TADHA molecule near the electrode, denoted as Type I-1; (2) the ethynylene site on one arm of TADHA molecule, denoted as Type I-2; (3) 9,10-dihydroanthracene core site, denoted as Type I-3; (4) the terminal sulphur atom site, denoted as Type I-4 (See Fig. 1). The calculations of ground-state-energy show that, the affinities for the  $H_2O$  molecule adsorbed as Type I-1, 2, 3 and 4 are about 0.09, 0.2, 0.15 and 0.78 eV, respectively, which suggests that the  $H_2O$  molecule is more likely to be adsorbed on the terminal S atoms, and then is the triple bond of TADHA molecule. The affinities also show that the adsorptions are very weak compared to the covalent bond.

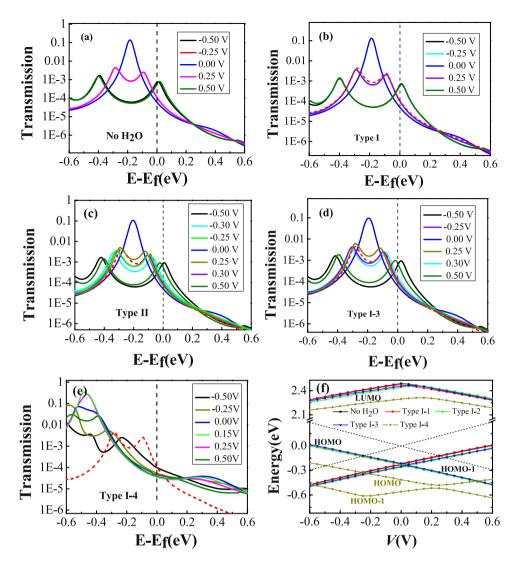


**Figure 2.** Electronic transport properties of TADHA molecular junction without or with one H<sub>2</sub>O molecule adsorbate, (a) Current and (b) Differential conductance as functions of applied bias voltage.

Figure 2 shows the current and the differential conductance as functions of applied bias for the TADHA molecular junctions without H<sub>2</sub>O adsorbate or with one H<sub>2</sub>O molecule being adsorbed on different sites of TADHA molecule. The figure shows that for the molecular junction without H<sub>2</sub>O molecule adsorbate, the molecular system shows symmetric electronic transport characters with respect to the positive and negative bias. Since the current shows peak values at about  $\pm 0.25$  V, the NDC behavior appears in the differential conductance curve when the absolute value of the applied bias is larger than 0.25 V. The peak values of the NDC are presented at about  $\pm 0.35$  V, which is a lower-bias NDC behavior as the experiment detected 60. Since the molecular junction may be destroyed and the interface configuration may be deformed by high bias voltage and thermal vibration at room temperature<sup>14</sup>, one can expect that the low-bias NDC behavior is a very desirable function of molecular device in the future. When one H<sub>2</sub>O molecule is adsorbed on the TADHA molecule, the current and the differential conductance in the negative bias regime for the Type I-1, 2 and 3 molecular junctions show a little difference compared with those of the molecular junctions without the H<sub>2</sub>O adsorbate. However, in the positive bias regime for the voltage larger than 0.2 V, the TADHA molecular system seems more conductive with Type I-3 configuration (see Fig. 2). At the meantime, the peak values of the current and the differential conductance are shifted slightly to higher bias regime as well as the peak values of the NDC. It is noticeable that the NDC behavior of the molecular junction in the low bias regime is destroyed when the  $H_2O$  is adsorbed on the terminal S site (Type I-4). At the same time, the low-bias current is depressed by about one order in the magnitude, which is similar to the molecular junctions probed by Long et al.<sup>28</sup>.

In order to understand the NDC behavior of the TADHA molecular junction and the  $H_2O$ -adsorbate effects, we presented the transmission spectra for the bias voltages of  $0.0 \, \text{V}$ ,  $\pm 0.25 \, \text{V}$ ,  $\pm 0.5 \, \text{V}$  and the voltage of peak-current in Fig. 3. Due to the contributions of the highest occupied molecular orbital (HOMO) and HOMO-1 to the electronic transmission and the degenerate of these two molecular orbitals, a high transmission peak is presented at about  $-0.2 \, \text{eV}$  for the transmission curve with zero bias as Fig. 3(a) shows. When the bias is applied, the degenerate of the two molecular orbitals is destroyed by the Stark effect of the bias, which further splits the high transmission peak into two lower transmission peaks. Because of the split of the transmission peak, the transmission probability at Fermi energy level slightly increases with the increase of the bias in the lower bias regime. However, due to the rapid decrease of the height of the split transmission peaks with the increase of the bias, the area under the transmission curve in the bias window increases at first and reaches a peak value at about 0.25 V, and then decreases with the increase of the bias, which depends on the rivalry of the width of the bias window and the mean height of transmission spectra in bias window. Thus a current peak appears at about 0.25 V as well as the NDC behavior for the TADHA molecular junction without  $H_2O$  adsorbate.

As for one H<sub>2</sub>O molecule adsorbed on the TADHA molecular junction, due to the strong electronegativity of the O atom, the TADHA molecular orbitals are modulated differently with the H<sub>2</sub>O molecule adsorbed on different positions, which further induces different changes of the transmission spectra as well as the conductance of the molecular system. In detail, for Type I-1 adsorption, since the H<sub>2</sub>O molecule is very close to the electrode and the affinity is very weak, the applied bias dominates the split of the energy levels and suppresses the effect of the H<sub>2</sub>O molecule by the electrodes, hence the transmission spectra show little difference from those of the TADHA molecular junction without H<sub>2</sub>O adsorbate (Fig. 3(b)). However, for Type I-2 and Type I-3 adsorption, the strong electronegativity of the O atom depresses the energy of the molecular orbital which close to it (Fig. 3(f)). Taking Type I-3 system as an example, since the  $H_2O$  molecule is closer to the left branch of TADHA molecule, the energy of the orbital which locates on the left arm of TADHA molecule is lowered down, while the energy of the orbital which locates on the right branch of TADHA molecule is almost unaltered by the H<sub>2</sub>O molecule. As for positive bias, the HOMO is lowered, whereas the HOMO-1 is little influenced. Thus the transmission peaks are less separated with positive bias compared with that of the molecular junction without the  $H_2O$  adsorbate. Consequently, the heights of the transmission peaks decrease a little more slowly in the split process with the increase of the positive bias than with negative bias, which can be easily seen by comparing the transmission curve of Type I-3 molecular system with that of the molecular system without H<sub>2</sub>O adsorbate at 0.25 V (Fig. 3(d)). Therefore, due to the effect of the H<sub>2</sub>O molecule on the HOMO and further on the transmission spectra, the TADHA molecular system with Type I-3 configuration shows more conductive when the bias is larger than 0.25 V, and the NDC



**Figure 3.** Transmission spectra and evolutions of the frontier molecular orbitals of TADHA molecular junctions. (a) Transmission spectra of TADHA molecular junction without  $H_2O$  adsorbate; (b), (c), (d) and (e) Transmission spectra of TADHA molecular junction with one  $H_2O$  adsorbate as Type I-1, 2, 3 and 4 molecular systems that are shown in Fig. 1. The red dashed lines in (b), (c) (d) and (e) are the transmission spectra of TADHA molecular junction without  $H_2O$  adsorbate at 0.25 V bias voltage, which are used as reference curves in these four figures. (f) The energy of LUMO, HOMO and HOMO-1 as functions of bias voltage with one or without  $H_2O$  adsorbate, the dashed line in (f) denotes bias windows.

behavior begins from a little higher bias voltage compared with that of the molecular system without  $H_2O$ . On the contrary, for the negative bias, when the transmission peak is split, the  $H_2O$  adsorbate is closer to HOMO-1, which results in a little red-shift of transmission peak corresponding to HOMO-1, while the transmission peak which corresponds to HOMO is almost unaltered. Since the HOMO-1 is shifted to the lower energy area and is apart from the bias window, one can easily understand why the current is changed very little by the  $H_2O$  molecule in the negative bias regime. Different from the transmissions of Type I-1, 2 and 3 molecular systems, the transmission peaks are shifted to much lower energy regime by the strong influence of  $H_2O$  adsorbate for Type I-4 system at lower bias. As Fig. 3(e) shows, the transmission peak related to the HOMO appears at about  $-0.4\,\mathrm{eV}$ , which is about  $0.2\,\mathrm{eV}$  lower than those of other type molecular junctions. Thus, with lower bias, the transmissions of Type I-4 system in the bias windows are evidently smaller than the other cases, which results in the poor current of Type I-4 molecular junction in the lower bias regime. With the increase of the negative bias, the transmission peak corresponding to the HOMO is blue-shifted and gradually enters bias window (Fig. 3(f)). However, with the increase of the positive bias, the transmission peak corresponding to the HOMO is shifted very little. Therefore, the current begins increasing from relatively lower bias in the negative bias regime compared with positive bias.

In order to gain deep insight into the NDC behavior, we presented spatial distributions of the HOMOs and HOMOs-1 for TADHA molecular systems at  $0.0 \, \text{V}$ ,  $\pm 0.5 \, \text{V}$  and at the peak-current voltages in Fig. 4. The figure shows that, at  $0.0 \, \text{V}$ , due to the approximate degeneration, the HOMO and HOMO-1 are both delocalized over the whole TADHA molecule not only for the molecular junction without  $\text{H}_2\text{O}$  molecule, but also for the

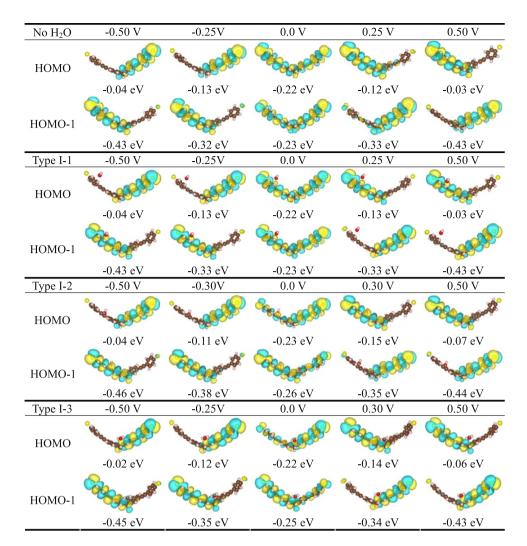
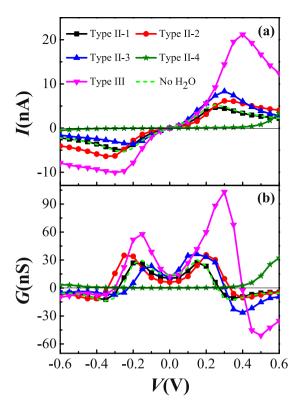


Figure 4. Spatial distributions of molecular orbitals for TADHA molecular junctions with one or without  $H_2O$  adsorbate at 0.0 V,  $\pm 0.5 \text{ V}$  and at the voltage of peak-current values, where the orbital energies relative to the Fermi level are also shown under each orbital.

molecular junction with Type I-1, 2 and 3 configurations, which results in the high transmission peaks at about −0.2 eV for these molecular junctions at 0.0 V. However, there are still some differences for the effects of the H<sub>2</sub>O molecule on the orbital distributions at 0.0 V, such as for Type I-2 and 3 molecular systems. Attributing to the depressing of the H<sub>2</sub>O molecule, the gaps between the HOMO and HOMO-1 are slightly enlarged compared with the molecular system without the H<sub>2</sub>O molecule, and the spatial distributions of the orbitals are obviously asymmetric to the two branches of TADHA molecule. However, for Type I-1 molecular system, the orbitals are little influenced by the H<sub>2</sub>O molecule since the adsorption of H<sub>2</sub>O molecule is very weak. For the molecular junctions at peak-current voltage or at ±0.5 V, the HOMOs and the HOMOs-1 have been pulled apart by bias and each only locates on one branch of the TADHA molecule. Thus one can easily understand why the height of the transmission peaks decrease very quickly in the split process with the increase of the bias voltage. We should mention that the orbitals presented in the figure are the molecular projected self-consistent Hamiltonian (MPSH) eigenstates, which are often used to discuss the electronic transport properties of molecular junctions in literatures<sup>7,23</sup>. The MPSH is the self-consistent Hamiltonian of the functional molecule including the H<sub>2</sub>O adsorbates with the influence of the electrode, which contains the electrode-molecule coupling effects but does not contain the Hamiltonian of the gold electrode, so the energies of the MPSH eigenstates are not perfectly consistent with the positions of the transmission peaks<sup>7</sup>.

More  $H_2O$  molecules or  $H_2O$  aggregate adsorption. In order to understand the effect of  $H_2O$  molecules on the electronic transports more explicitly, we further set two or more  $H_2O$  molecules adsorbed on the TADHA molecule, which are shown in Fig. 1, where Type II-1, 2 and 3 are the molecular junctions with two  $H_2O$  molecules being adsorbed on TADHA molecule, Type III is the molecular junction with three  $H_2O$  adsorbates. After geometric optimizations, we calculated the electronic transport properties for the molecular systems with Type II and Type III configurations. Figure 5 shows the current and the differential conductance of TADHA molecular junctions with two or three  $H_2O$  adsorbates as functions of applied bias. From the figure one can see that, TADHA molecular junctions still show low-bias NDC behaviors with the influence of two or three  $H_3O$ 

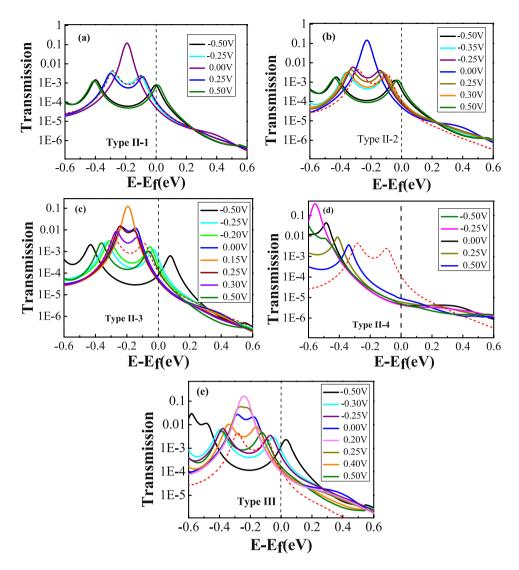


**Figure 5.** Electronic transport properties of TADHA molecular junction with two or three  $H_2O$  molecule adsorbates. (a) Current and (b) Differential conductance as functions of applied bias voltage.

molecules adsorbed on the backbone of TADHA molecule. For the Type II-1 and Type II-2 molecular junctions, the electronic transport properties show similar characteristics to Type I molecular systems. In detail, due to the influences of the  $\rm H_2O$  molecules adsorbed near the electrodes being suppressed by bias voltage, the electronic transport properties of Type II-1 (see Figs 5 and 6(a)) are very similar to those of Type I-1 molecular system and the molecular system without  $\rm H_2O$  adsorbate. For the Type II-2 molecular system, since the  $\rm H_2O$  molecule adsorbed on the ethynylene site can depress the energy of the frontier molecular orbital which close to the  $\rm H_2O$  molecule and consequently induces red-shift of the transmission peaks, the peak value of the current is shifted to higher bias voltage compared to the ones without  $\rm H_2O$  adsorbate (see Figs 5 and 6(b)). Since the influences of the two  $\rm H_2O$  molecules are nearly symmetric to the TADHA molecular junctions, the current curves and the conductance curves are both approximately symmetric to the positive and negative bias for the junctions with Type II-1 and Type II-2 configuration. Attributing to the approximately symmetric effects of the two  $\rm H_2O$  molecules, at 0.0 V, the spatial distributions of HOMO and HOMO-1 for Type II-1 and Type II-2 molecular systems also present approximately symmetric character to the two branches of the TADHA molecule (Figure S1).

Our calculations show that, if we first set two  $\rm H_2O$  molecules on the two conjugated rings of the 9,10-dihydroanthracene core respectively and perform geometric optimization, the two  $\rm H_2O$  molecules will move and aggregate with each other, until at last formed Type II-3 configuration, which obviously due to the electrostatic attraction originated from the strong polarity of  $\rm H_2O$  molecule. From Fig. 5 one can see that, the current and the differential conductance curves of Type II-3 system are more asymmetric than those of Type I-3. The peak current value is further enhanced and the peak NDC value is more than doubled of that without  $\rm H_2O$  adsorbate for the junction in the positive bias regime, whereas for the negative bias, which is obviously depressed by the influence of the  $\rm H_2O$  adsorbates. Thus, for TADHA molecular junction with Type II-3 configuration, the adsorption of  $\rm H_2O$  molecules induces apparent rectifier behavior with the maximum rectification ratio of 2.74 at 0.35 V.

Figure 6(c) shows that, for Type II-3 molecular system, due to the depressing of the two  $H_2O$  molecules to the molecular orbitals, the HOMO and HOMO-1 are not degenerated at zero bias, thus the transmission spectrum shows two peaks at about  $-0.15\,\mathrm{eV}$  and  $-0.24\,\mathrm{eV}$  corresponding to the HOMO and HOMO-1. With the increase of the positive bias, the HOMO is depressed and simultaneously the HOMO-1 is enhanced. When the bias is increased to about 0.15 V, the HOMO and HOMO-1 are re-degenerated, which results in the combination of the two transmission peaks into one higher transmission peak at 0.19 eV. Hence, the TADHA molecular junction with Type II-3 configuration is more conductive in the positive bias regime. Different from positive bias, the negative bias further splits and depresses the two transmission peaks which makes the molecular junction less conductive when the bias less than  $-0.20\,\mathrm{V}$ , so the TADHA molecular junction shows rectifier behavior. In fact, from the asymmetric evolution of the HOMO and HOMO-1, especially, the degeneration point of the HOMO and HOMO-1 obviously deviates from 0.0 V (Figure S2), one can also understand the rectifier behavior of Type II-3 molecular system, because the degeneration of the HOMO and HOMO-1 results in the delocalization of the HOMO and HOMO-1 (Figure S1), and consequently enhances the current of positive bias regime.



**Figure 6.** Transmission spectra of TADHA molecular junctions. (a), (b), (c) and (d) Transmission spectra for the molecular junction with two  $H_2O$  adsorbates as Type II-1, 2, 3 and 4 molecular systems; (e) Transmission spectra for the molecular junction with three aggregated  $H_2O$  molecules being adsorbed on as Type III molecular systems. The red dashed lines in (a), (b), (c), (d) and (e) are the transmission spectra of TADHA molecular junction without  $H_2O$  adsorbate at 0.25 V bias voltage, which are used as reference curves in the figure.

Similar to one- $H_2O$ -molecule adsorption on S atom site, for the Type II-4 molecular system that each terminal S atom adsorbs one  $H_2O$  molecule, the NDC behavior of TADHA molecular junction has been destroyed absolutely in the lower bias regime. Due to the strong influence of the adsorbates, the conducting orbitals have been further depressed to lower than  $-0.5\,\mathrm{eV}$  (Fig. 6(d) and Figure S1), which results in much poorer conductance of Type II-4 molecular system compared with the molecular system without  $H_2O$  adsorbate or with one  $H_2O$  molecule adsorbed on the terminal S atom. The numerical results show that, for the bias lower than  $0.25\,\mathrm{V}$ , the current of Type II-4 molecular system is about two orders lower than that of the system without the  $H_2O$  adsorbate in the magnitudes, which is in good agreement with Long's experiment<sup>28</sup>. Although with the increase of the positive bias, the transmission peak corresponding to the HOMO is shifted to higher energy regime, it is still out of the bias window when the bias is enhanced to  $0.5\,\mathrm{V}$  (Figure S2). So the current is very weak for the Type II-4 molecular junction.

### Discussion

It is interesting that, for the  $H_2O$  molecules being adsorbed on the backbone of TADHA molecule, the aggregate of  $H_2O$  molecules seems to have stronger influence on the electronic transport properties of TADHA molecular junction than single or separated  $H_2O$  molecules. Especially, with the influence of the aggregate of  $H_2O$  molecules adsorbed on one branch of TADHA molecule, the values of the current and NDC peaks are both enhanced dramatically. Taking the aggregate of three  $H_2O$  molecules as an example, after geometric optimization we obtained the configuration of Type III molecular junction (Fig. 1). From Fig. 5 one can see that the peak-current value

is up to about 21 nA, which is more than four times than that for the system without  $H_2O$  adsorbate. Similar to Type II-3 molecular system, the depression of the  $H_2O$  aggregate destroys the degeneration of the HOMO and HOMO-1 at zero bias, and consequently splits the high transmission peak at about  $0.2\,\mathrm{eV}$  (Fig. 6(e)). Since the transmission spectra near Fermi energy is changed very slightly, the current is slightly changed in the lower bias regime. However, when the HOMO and HOMO-1 are re-degenerated at the positive bias of about  $0.2\,\mathrm{V}$ , the two transmission peaks which are related to the HOMO and HOMO-1 are combined into one high peak. Further enhancing the positive bias after the two orbitals re-degeneration, the combined transmission peak is re-split, and compared with former cases, the transmission peak corresponding to HOMO enters bias window with a higher height. For example, at  $0.25\,\mathrm{V}$  and  $0.4\,\mathrm{V}$ , the height of the transmission peak related to the HOMO is about  $0.05\,\mathrm{and}\,0.01$ , respectively. However, except for the Type II-3 with an aggregate of two  $H_2O$  molecules, the heights of the transmission peaks corresponding to the HOMO are all no more than  $0.004\,\mathrm{for}$  the other cases at  $0.25\,\mathrm{V}$ , not to mention at  $0.4\,\mathrm{V}$ . Thus, when the currents of other cases reach the peak values at about  $0.25-0.30\,\mathrm{V}$ , the current of Type III system still increases rapidly until reaches a much higher current peak at  $0.4\,\mathrm{V}$ . Then due to the rapid shrink of the transmission peak which is induced by the further split of the HOMO and the HOMO-1, the current decreases quickly and results in larger NDC behavior.

As to the accuracy of our work, we found that our calculations successfully reproduced the low-bias NDC behavior of TADHA molecular junction that was investigated experimental by Perrin  $et\ al.^{60}$ . However, the absolute values of the current in the lower bias regime are about one order of magnitude larger than the experimental results. According to the studies of Quek  $et\ al.^{61-63}$ , the HOMO-LUMO (LUMO: lowest unoccupied molecular orbital) gap is usually underestimated in standard density functional theory (DFT), which results in overestimate of conductance of single molecular junction. Thus an alternative DFT-based approach  $^{61-65}$  (e.g. DFT +  $\Sigma$  approach) is needed to give more accurate and physically meaningful understandings of electron-transport properties of TADHA molecular junction in the future. Since the HOMO is much closer to the Fermi level than the LUMO, the electron-transport properties are mainly governed by the HOMO. According to the DFT +  $\Sigma$  method in the literatures  $^{61-63}$  and the experimental results  $^{60}$ , we can roughly estimate that, for the TADHA molecular junction without  $\rm H_2O$  adsorbate, the HOMO is overestimated by not more than 0.3 eV relative to the Fermi level, which is much smaller than those of weak coupling systems  $^{61-63}$ .

In summary, the NDC behavior of TADHA molecular junctions and the  $\rm H_2O$  adsorption effect are investigated by applying the density-functional theory and non-equilibrium Green's function method. In the lower bias regime, the TADHA molecular junction exhibits excellent NDC behavior, which is attributed to the splitting of the degenerated transmission channels at applied bias voltage. The  $\rm H_2O$  molecules may depress the energy of the transmission channel, and further influence the electronic transport properties of the molecular junction. The influences of the  $\rm H_2O$  molecules are closely related to the  $\rm H_2O$  molecule affinity. Although the single  $\rm H_2O$  molecule or the separated  $\rm H_2O$  molecules adsorbed on the backbone of TADHA molecule can lower the energies of the TADHA molecular orbitals and shift the positions of the transmission peaks, they have relatively smaller effects on the current and NDC behavior of the TADHA molecular junction. The aggregate of several  $\rm H_2O$  molecules adsorbed on one branch of the TADHA molecule can strongly enhance the current and the NDC behavior of the molecular junction. The  $\rm H_2O$  molecule adsorbed on the terminal S atom strongly depresses the conductive orbitals, which further dramatically suppresses the current of TADHA molecular junction in the lower bias regime and consequently destroys the low-bias NDC behavior of the molecular junction.

#### Methods

The geometric structures of TADHA molecular systems without or with  $H_2O$  molecules were optimized using the SIESTA package with a maximum force  $0.02\,\text{eV}/\text{Å}^{66,\,67}$ . The Troullier–Martin type norm-conserving pseudopotentials are applied to represent the core electrons<sup>68</sup>, the generalized gradient approximation (GGA) with Perdew–Burke–Ernzerhof (PBE) formulation is applied as the exchange-correlation functional<sup>69</sup>. For Au atoms, a single- $\zeta$  plus polarization basis set is used, and for other atoms, a double- $\zeta$  plus polarization basis set is employed.

The current through the molecular device with different bias voltage is obtained according to the Landauer–Buttiker formula<sup>70</sup>

$$I = \frac{2e}{h} \int T(E, V) [f(E - \mu_{L}) - f(E - \mu_{R})] dE,$$
 (1)

which was calculated with the TranSIESTA module of the SIESTA package. In Eq. (1), T(E,V) is the transmission probability, which depends on the incident energy E of the transmission electrons and the applied bias voltage V.  $\mu_L$  and  $\mu_R$  in the Fermi–Dirac distribution functions f(E) are the electrochemical potentials of the two electrodes. The transmission probability T(E,V) is calculated by NEGF method. The differential conductance is defined as  $G=\partial I/\partial V$ . In the electron transport calculations, a 300 Ry mesh cutoff for the real space grid was chosen. The convergence criterion for density matrix was set to  $1.0\times 10^{-4}$ . A  $4\times 4$  k-point grid was used for the Brillouin-zone (BZ) sampling in the transverse directions. A 300 K smearing was applied for the electronic Fermi-Dirac distribution.

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#### **Acknowledgements**

This work was supported by the National Natural Science Foundation of China (Grant Nos. 11374195 and 11304185) and the Natural Science Foundation of Shandong province, China (Grant No. ZR2013FM006). Thanks to the supporting of Taishan scholar project of Shandong Province.

#### **Author Contributions**

All authors provided essential contributions to the manuscript and the project. All authors have given approval to the final version of the manuscript. Z.L.L., X.H.Y. and R.L. contributed the ideas and discussed the manuscript in detail. X.H.Y., R.L., J.J.B. and H.Y.F. performed the calculations and the data analysis. G.P.Z., Y.Z.S. and C.K.W. discussed some details with the corresponding author.

## **Additional Information**

**Supplementary information** accompanies this paper at doi:10.1038/s41598-017-04465-3

**Competing Interests:** The authors declare that they have no competing interests.

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